NSN 5961-00-018-1926

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View Online at https://aerobasegroup.com/nsn/5961-00-018-1926 **Inclosure Material:** Metal **Overall Length:** 1.196 inches **Overall Diameter:** 0.687 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-61 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Overall Width Across Flats:** 0.687 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 120.0 collector to base voltage/static/emitter open and 80.0 collector to emitter voltage/static/base open and 10.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 5.00 amperes source cutoff current and 5.00 amperes source cutoff current blank **Power Rating Per Characteristic:** 50.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug

N/a

Specification Data:

Unit Of Measure:

Shelf Life:

80131-release4254 professional/industrial association specification

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Demilitarization:

No

Fiig:

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